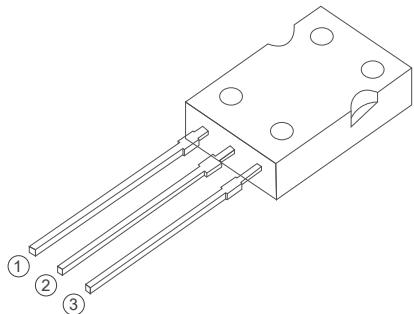


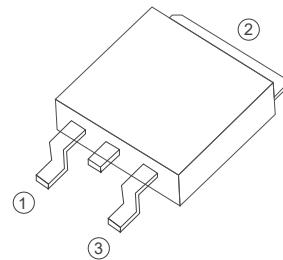
BT134 Series  
4A TRIACs  
4 Quadrants TRIACs



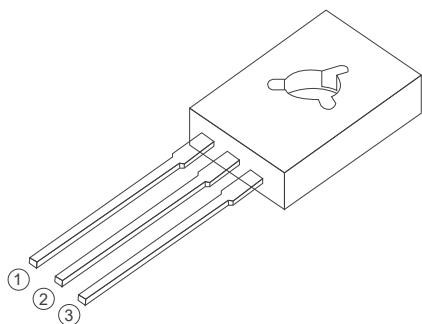
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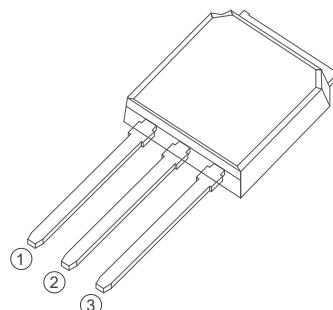
SOT-82(TO-126P)



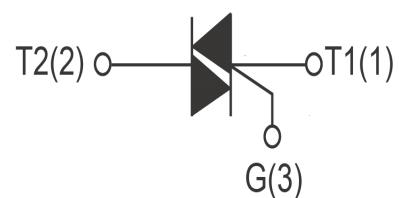
TO-252



TO-126



TO-251



## FEATURES

- > IT(RMS): 4A
- > VGT: 1.5V
- > VDRM VRRM:800V

## APPLICATIONS

Washing machine, vacuums, massager, solid state relay, AC Motor speed regulation and so on.

## Absolute Maximum Ratings ( $T_j=25^\circ\text{C}$ unless otherwise specified)

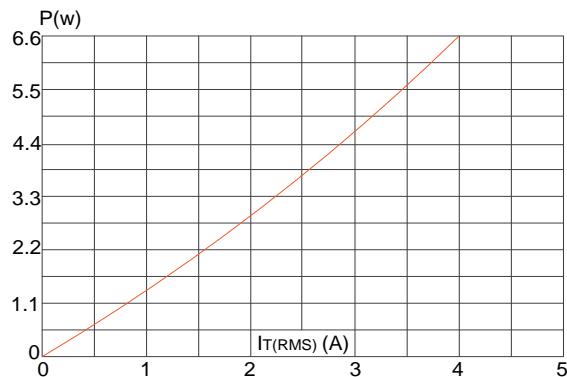
Symbol	Parameter	Conditions	Ratings	Unit
VDRM VRRM	Repetitive Peak Off-State Voltage	BT134-600	600	V
IT(RMS)	R.M.S On-State Current	$T_c=110^\circ\text{C}$	4	A
ITSM	Surge On-State Current	$t_p=16.7\text{ms}/t_p=10\text{ms}$	25/27	A
$I^2t$	$I^2t$ for fusing	$T_p=10\text{ms}$	3.1	$\text{A}^2\text{s}$
PG(AV)	Average Gate Power Dissipation	$T_j=125^\circ\text{C}$	0.5	W
IGM	Peak Gate Current	$t_p=20\mu\text{s } T_j=125^\circ\text{C}$	2	A
$T_j$	Operating Junction Temperature		$\sim 40 \sim 125$	$^\circ\text{C}$
TSTG	Storage Temperature		$\sim 40 \sim 150$	$^\circ\text{C}$

## Electrical Characteristics ( $T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Value		Unit	
			D	E		
IDRM	Repetitive Peak Off-State Current	$T_j=25^\circ\text{C}$	$\leq 10$		uA	
		$T_j=125^\circ\text{C}$	$\leq 0.5$		mA	
IRRM	Repetitive Peak Reverse Current	$T_j=25^\circ\text{C}$	$\leq 10$		uA	
		$T_j=125^\circ\text{C}$	$\leq 0.5$		mA	
VTM	Forward "on" voltage	$IT=5\text{A } t_p=380\mu\text{s}$	$\leq 1.7$		V	
VGD	gate non-trigger voltage	$VD=12\text{V}, T_j=125^\circ\text{C}$	$\geq 0.2$		V	
IH	Holding current	$VD=12\text{V }, IGT=0.1\text{A}$	$\leq 10$	$\leq 15$	mA	
VGT	Gate trigger voltage	$VD=12\text{V}$	$\leq 1.5$		V	
IGT	Gate trigger current	I,II,III	$VD=12\text{V}, IGT=0.1\text{A}$	$\leq 5$	$\leq 10$	mA
		IV		$\leq 10$	$\leq 25$	
di/dt	Critical-rate of rise of commutation current.	I,II,III	$IT=6\text{A }, IGT=0.2\text{A}, dIg/dt=0.2\text{A/us}$	$\geq 50$		A/us
		IV		$\geq 10$		
dv/dt	Critical-rate of rise of commutation voltage		$T_j=125^\circ\text{C } VD=2/3VDRM$ Gate open circuit	$\geq 5$	$\geq 50$	V/us

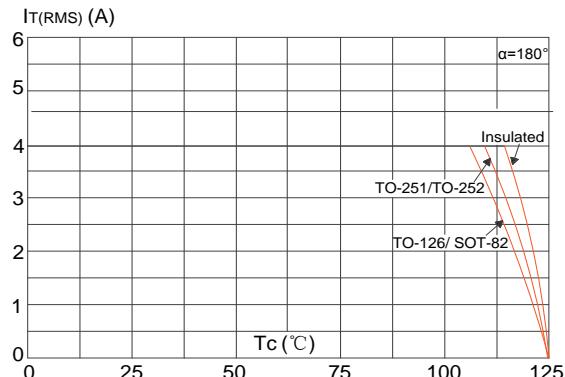
**FIG1**

Maximum power dissipation versus RMS on-state current



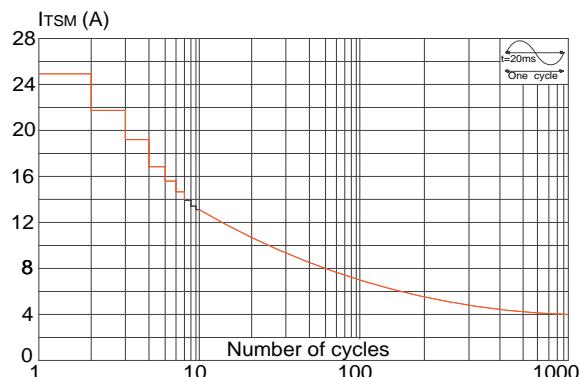
**FIG2**

RMS on-state current versus case temperature



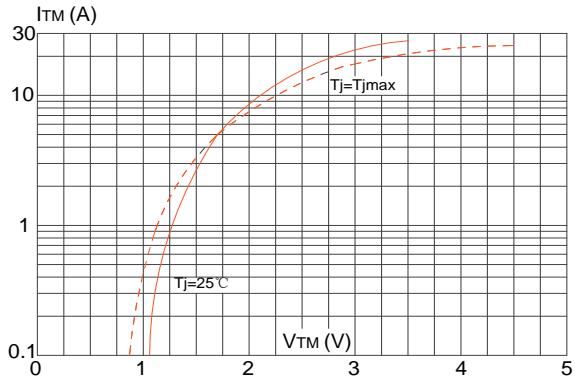
**FIG3**

Surge peak on-state current versus number of cycles



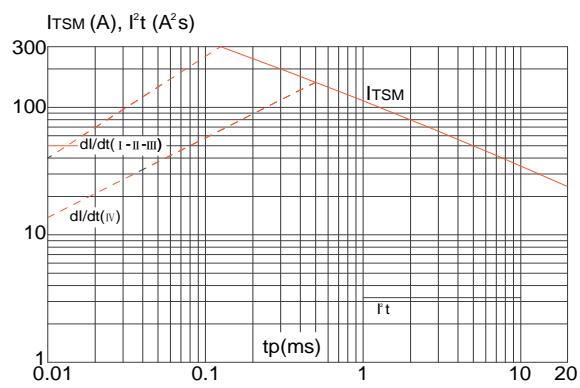
**FIG4**

On-state characteristics (maximum values)



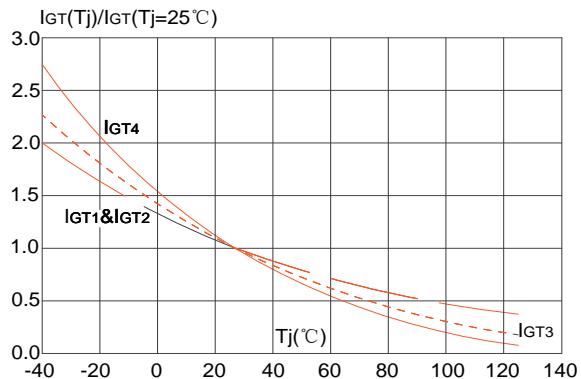
**FIG5**

Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20\text{ms}$ , and corresponding value of  $I^2t$  ( $dI/dt < 100\text{A}/\mu\text{s}$ )



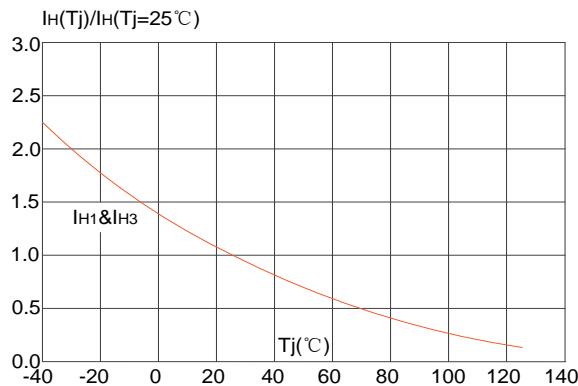
**FIG6**

**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature



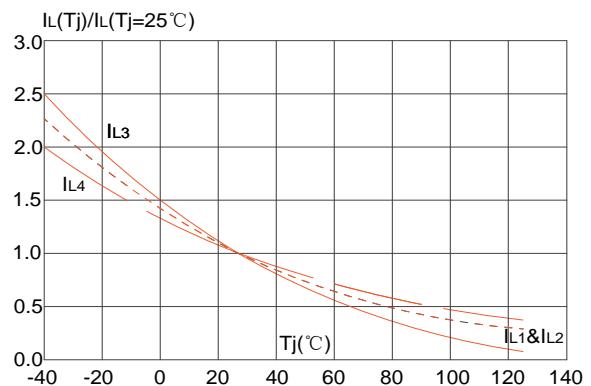
**FIG7**

**FIG.7:** Relative variations of holding current versus junction temperature

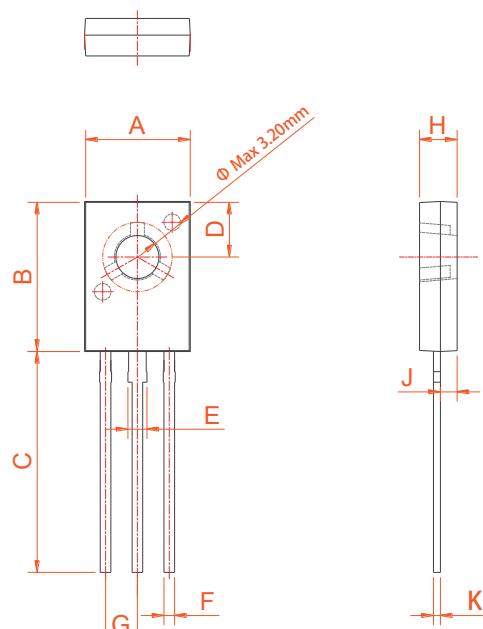


**FIG8**

**FIG.8:** Relative variations of latching current versus junction temperature



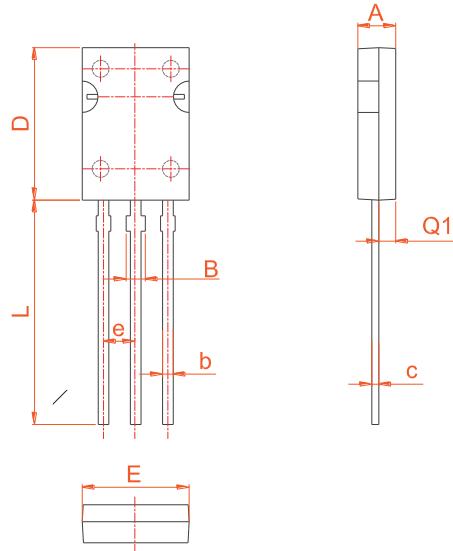
## PACKAGE MECHANICAL DATA



TO-126

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	7.40		7.80	0.291		0.307
B	10.6		11.2	0.417		0.441
C	15.3		16.3	0.602		0.642
D	3.90		4.10	0.154		0.161
E	1.17		1.47	0.046		0.058
F	0.66		0.86	0.026		0.034
G		2.29			0.090	
H	2.50		2.90	0.098		0.114
J	1.10		1.50	0.043		0.059
K	0.45		0.60	0.018		0.024

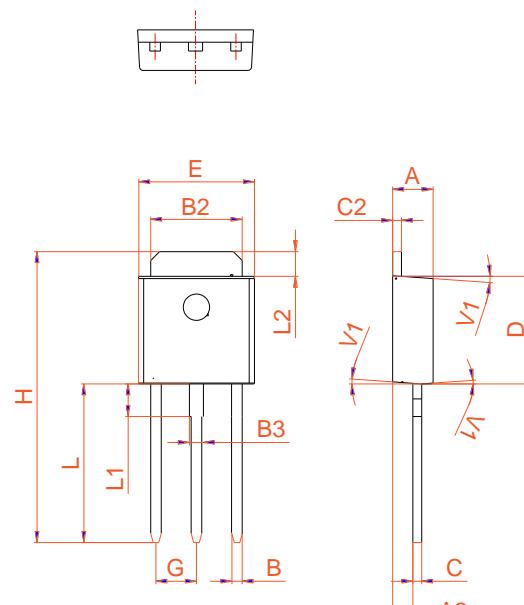
## PACKAGE MECHANICAL DATA



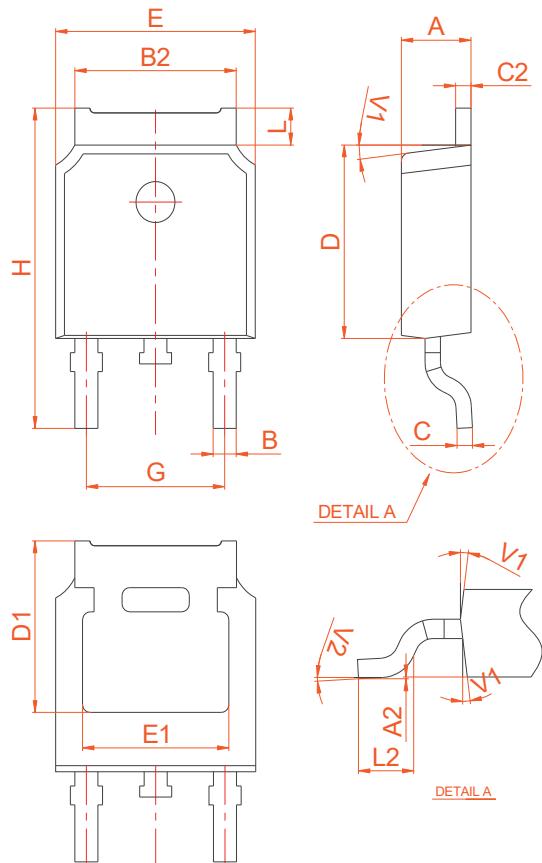
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.45	2.55	2.65	0.096	0.100	0.104
b	0.71	0.76	0.81	0.028	0.030	0.032
B	1.27	1.37	1.45	0.050	0.054	0.057
c	0.48	0.50	0.52	0.019	0.020	0.021
D	10.60	10.80	11.00	0.417	0.425	0.433
E	7.30			7.70	0.287	
e	2.24	2.29	2.34	0.088	0.090	0.092
L	15.30	15.60	15.90	0.602	0.614	0.626
Q1	1.17	1.27	1.37	0.046	0.050	0.054

SOT-82

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.20		2.40	0.086		0.095
A2	0.90		1.20	0.035		0.047
B	0.55		0.65	0.022		0.026
B2	5.10		5.40	0.200		0.213
B3	0.76		0.85	0.030		0.033
C	0.45		0.62	0.018		0.024
C2	0.48		0.62	0.019		0.024
D	6.00		6.20	0.236		0.244
E	6.40		6.70	0.252		0.264
G		2.30		0.091		
H	16.0		17.0	0.630		0.669
L	8.90		9.40	0.350		0.370
L1	1.80		1.90	0.071		0.075
L2	1.37		1.50	0.054		0.059
V1		4°		4°		



TO-251

**PACKAGE MECHANICAL DATA**


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.20		2.40	0.086		0.095
A2	0.03		0.23	0.001		0.009
B	0.55		0.65	0.022		0.026
B2	5.10		5.40	0.200		0.213
C	0.45		0.55	0.018		0.022
C2	2.70		2.90	0.106		0.114
D	6.00		6.20	0.236		0.244
E	6.40		6.70	0.252		0.264
G	4.40		4.70	0.173		0.185
H	9.35		10.6	0.368		0.417
L1	1.30		1.70	0.051		0.067
L2	1.37		1.50	0.054		0.059
L3		0.8			0.031	
L4		0.8			0.031	
V1		4°			4°	
V2	0°		8°	0°		8°

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